

Supporting Information

Balancing the performance and stability in organic photodiodes with all polymer active layer

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1. Photoelectron spectroscopy in air (PESA) measurements

Photoelectron spectroscopy in air (PESA) measurements were recorded using a Riken Keiki PESA spectrometer with a power setting of 10 nW and a power number of 0.3. Samples for PESA were prepared on glass substrates.¹

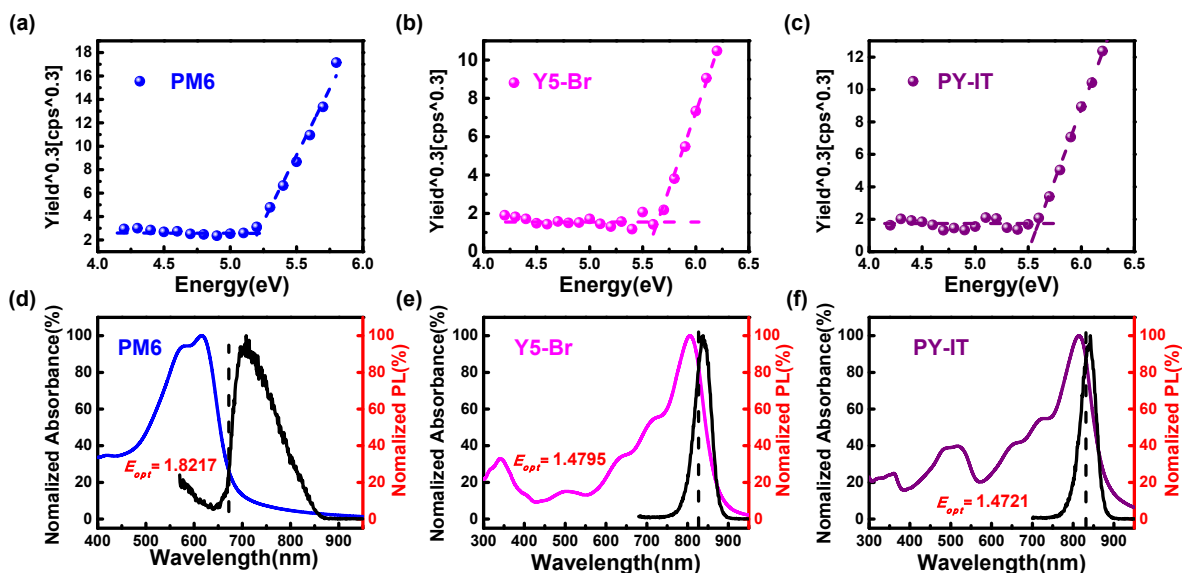


Fig. S1. The energy levels of (a) PM6, (b) Y5-Br and (c) PY-IT were investigated using a Photoelectron spectroscopy (PESA) in air. The normalized UV-Vis absorption and PL emission (black) spectra of (d) PM6, (e) Y5-Br and (f) PY-IT, respectively.

Table S1. The energy levels of materials were investigated using PESA.

Material	E_{HOMO} (eV)	$E_{\text{g}}^{\text{opt}}$ (eV)	E_{LUMO} (eV)
PM6	-5.22	1.82	-3.40
Y5-Br	-5.64	1.48	-4.16
PY-IT	-5.59	1.47	-4.12

2. Device Characterization

Current density-voltage ($J-V$) curves of the devices were measured in a nitrogen-filled glove box using a Keithley 2400 Source Meter with an Enlitech solar simulator at AM 1.5G (100 mW cm^{-2}). The light intensity was calibrated using a standard single crystal silicon reference cell (with KG5 filter, purchased from PV Measurement to bring spectral mismatch to unity). The external quantum efficiency (EQE) was measured by a certified incident photon to electron conversion (IPCE) equipment (QE-R) from Enli Technology Co., Lt.

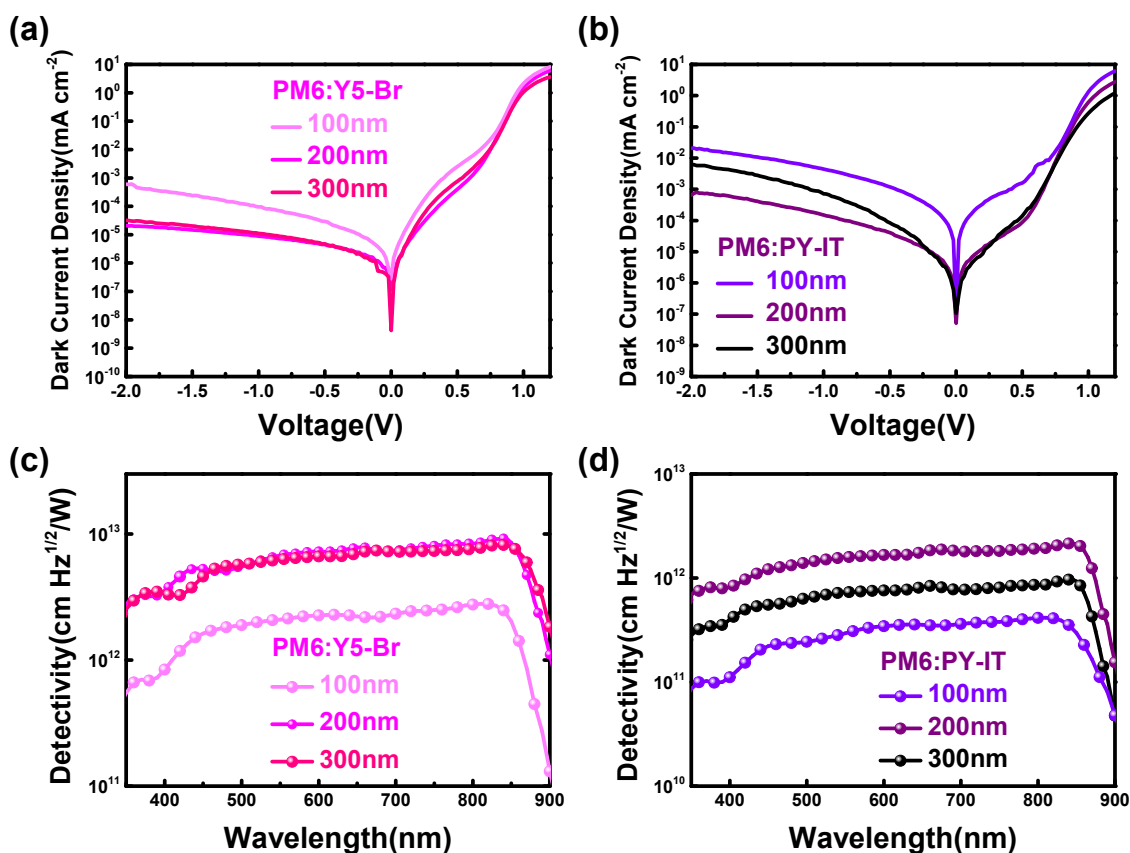


Fig. S2. (a, b) Dark $J-V$ characteristics; (c, d) Detectivity of the OPDs with PM6:Y5-Br and PM6:PY-IT depending on thickness of photosensitive layers.

3. UV-Vis Absorption

UV-Vis absorption spectra of different blend films were recorded on a PerkinElmer LAMBDA 365 UV-Vis spectrophotometer.

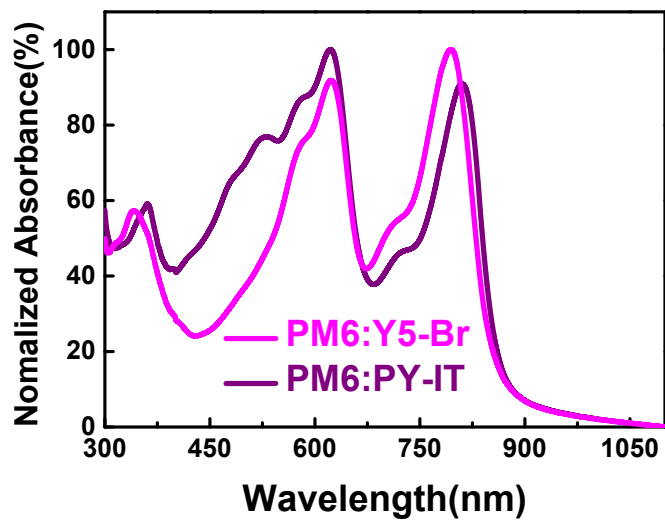


Fig. S3. Normalized UV-Vis absorbance spectra of PM6:Y5-Br and PM6:PY-IT in films.

4. SCLC Measurements

Electron-only and hole-only devices were fabricated for the $J-V$ measurements. The structure of electron-only device was ITO/ZnO/BHJ/PDIN/Ag and the hole-only was ITO/PEDOT:PSS/BHJ/MoO₃/Ag.² The single-carrier device was connected to a Source Measure Unit (Keithley, Model 236 SMU) which provides DC voltage to the electron-only devices. The $J-V$ values of different DC voltages can be detected and recorded through SMU, and trap density extracted by the space-charge-limited-current (SCLC) method.³

5. Photoluminescence measurements

The photoluminescence of the films were measured by a OmniFluo990LSP equipped with an integrating hemisphere at an excitation wavelength of 580 nm or 750 nm.

6. Atomic Force Microscopy (AFM) Imaging

A Dimension Icon atomic force microscope (AFM) from Bruker was used to image the active layers in tapping mode. The photosensitive layers were coated over PEDOT:PSS by methods described in Section of Device Fabrication.

7. Transmission Electron Microscopy (TEM) Characterization

Using PEDOT:PSS as a sacrificial layer on a glass substrate, the spun-cast film was peeled from the substrate by dissolving the PEDOT:PSS layer in water and then transferred onto a 50-mesh copper grid (Electron Microscopy China), and viewed by a spherical aberration-corrected electron microscope (Titan ETEM G2 E-Twin) operated at an acceleration voltage of 300 keV.

8. Grazing Incidence Wide-angle X-ray Scattering

Grazing-incidence wide-angle X-ray scattering (GIWAXS) was measured at a Pohang Light Source (Korea), beam line 3C. The incidence angle ($0.1^\circ \sim 0.14^\circ$) was carefully selected to allow for complete penetration of the X-rays into the film.⁴

Table S3. Fitting data obtained from GIWAXS in the in-plane (IP) and out-of-plane (OOP) directions of PM6:PY-IT blend films.

Component	Peak	Peak Location(\AA^{-1})	d-Space(\AA)	FWHM(\AA^{-1})	Crystal Coherence Length(\AA)
PM6:PY-IT As-cast	(IP) (100)	0.29	21.67	0.05	117.80
	(OOP) (010)	1.33	4.72	0.38	14.9
	(OOP) (010)	1.63	3.85	0.27	20.9
PM6:PY-IT Annealed	(IP) (100)	0.29	21.67	0.05	117.80
	(OOP) (010)	1.37	4.59	0.37	15.3
	(OOP) (010)	1.64	3.83	0.27	20.9

Table S4. Fitting data obtained from GIWAXS in the in-plane (IP) and out-of-plane (OOP) directions of PM6:Y5-Br blend films.

Component	Peak	Peak Location(\AA^{-1})	d-Space(\AA)	FWHM(\AA^{-1})	Crystal Coherence Length(\AA)
PM6:Y5-Br As-cast	(IP) (100)	0.29	21.67	0.06	102.80
	(OOP) (010)	1.52	4.13	0.56	10.1
	(OOP) (010)	1.64	3.83	0.23	24.6
PM6:Y5-Br Annealed	(IP) (100)	0.29	21.67	0.06	102.80
	(OOP) (010)	1.42	4.42	0.32	17.7
	(OOP) (010)	1.67	3.76	0.26	21.7

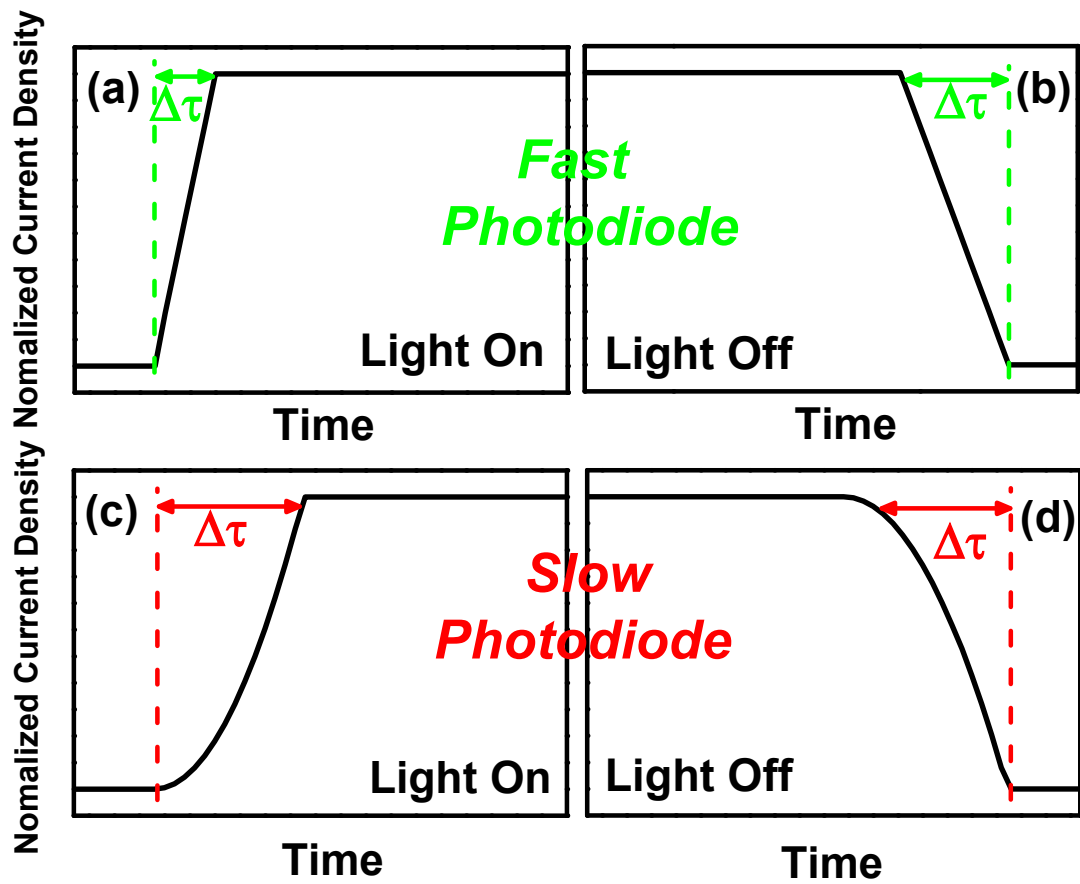


Fig. S4. Schematic illustration of the on-off response from fast and slow photodiodes.

9. References

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